

Small Outline Optoisolators

Transistor Output

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications, and eliminate the need for through—the—board mounting.

- Convenient Plastic SOIC-8 Surface Mountable Package Style
 - Standard SOIC-8 Footprint, with 0.050 Lead Spacing
- · Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input-Output Isolation of 3000 Vac (rms) Guaranteed
- • UL Recognized File #E90700, Volume 2

Ordering Information:

- •To obtain MOC211, 212 and 213 in Tape and Reel, add R2 suffix to device numbers: R2 = 2500 units on 13" reel
- •To obtain MOC211, 212 and 213 in quantities of 50 (shipped in sleeves) No Suffix

Marking Information:

- • MOC211 = 211
- • MOC212 = 212
- • MOC213 = 213

Applications:

- General Purpose Switching Circuits
- Interfacing and coupling systems of different potentials and impedances
- Regulation Feedback Circuits
- • Monitor and Detection Circuits

MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

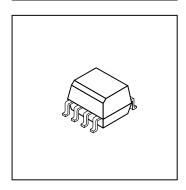
Symbol	Value	Unit
ΙF	60	mA
I _F (pk)	1.0	Α
٧R	6.0	V
PD	90 0.8	mW mW/°C
	I _F I _F (pk) V _R	IF 60 IF(pk) 1.0 VR 6.0 PD 90

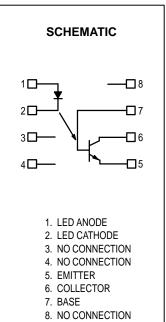
OUTPUT TRANSISTOR

Collector–Emitter Voltage	VCEO	30	V
Collector–Base Voltage	VCBO	70	V
Emitter–Collector Voltage	VECO	7.0	V
Collector Current — Continuous	IC	150	mA
Detector Power Dissipation @ T _A = 25°C Derate above 25°C	PD	150 1.76	mW mW/°C

MOC211 MOC212 MOC213

SMALL OUTLINE OPTOISOLATORS TRANSISTOR OUTPUT





MAXIMUM RATINGS — continued ($T_A = 25$ °C unless otherwise noted)

Rating	Symbol	Value	Unit
TOTAL DEVICE			
Input-Output Isolation Voltage ^(1,2) (60 Hz, 1.0 sec. duration)	VISO	3000	Vac(rms)
Total Device Power Dissipation @ T _A = 25°C Derate above 25°C	PD	250 2.94	mW mW/°C
Ambient Operating Temperature Range ⁽³⁾	TA	-45 to +100	°C
Storage Temperature Range ⁽³⁾	T _{stg}	-45 to +125	°C
Lead Soldering Temperature (1/16" from case, 10 sec. duration)	_	260	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

TYPICAL CHARACTERISTICS

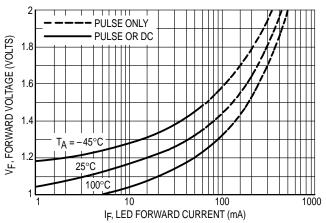


Figure 1. LED Forward Voltage versus Forward Current

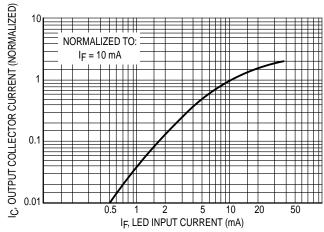
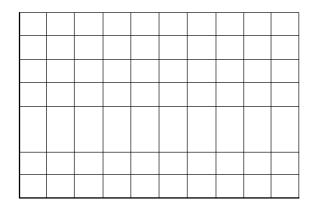
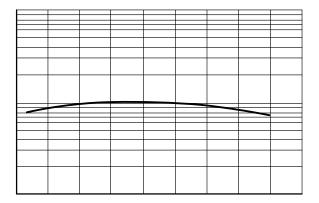
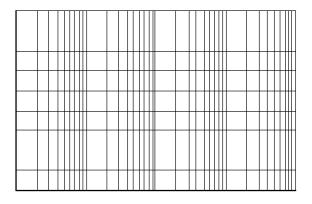


Figure 2. Output Current versus Input Current

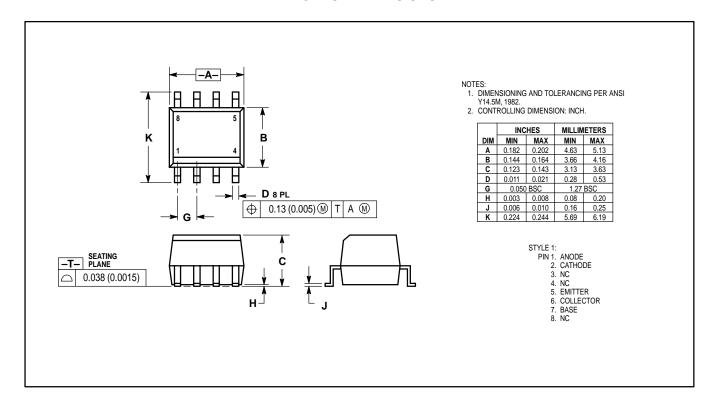








PACKAGE DIMENSIONS





DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.